

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







4 TO 40 GHz EVEN HARMONIC (1/2 LO) BALANCED MIXER

MODEL: SBE0440LW1

FEATURES

• RF coverage...... 4 to 40 GHz

• LO coverage 2 to 20 GHz

• IF operation...... DC to 1.5 GHz

• LO power range..... +10 to +15 dBm

 High carrier rejection of 30 dB typical when used as an upconverter

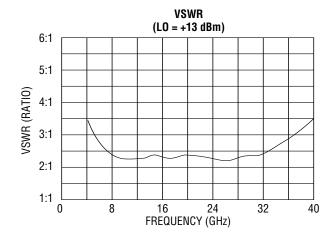


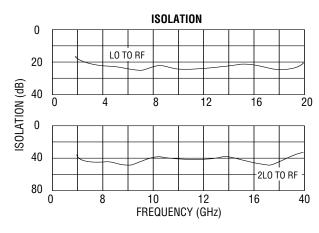
The SBE Series of mixers employs antiparallel ring diodes to achieve efficient RF-to-IF or IF-to-RF conversion using an LO at 1/2 the normal frequency. These units are particularly useful in miniature transceivers as upconverters, where high carrier rejection is desired without costly tunable filters or isolators.

NPUT PARAMETERS	CONDITION	UNITS	MIN.	TYP.	MAX.
RF frequency range		GHz	4		40
RF VSWR (RF = -10 dBm, LO = +13 dBm)	6 to 30 GHz	Ratio		2.5:1	
	4 to 40 GHz	Ratio		3.5:1	
LO frequency range		GHz	2		20
LO power range		dBm	+10	+13	+15
LO VSWR (LO = +13 dBm)	2 to 20 GHz	Ratio		2.75:1	
TRANSFER CHARACTERISTICS	CONDITION	UNITS	MIN.	TYP.	MAX.
Conversion loss (IF = 100 MHz, LO = +13 dBm)	6 to 30 GHz	dB		9	11
	4 to 40 GHz	dB		10	12
LO-to-RF isolation	2 to 20 GHz	dB		20	
2LO-to-RF isolation	4 to 40 GHz	dB	30	40	
LO-to-IF isolation	2 to 20 GHz	dB		20	
RF-to-IF isolation	2 to 20 GHz	dB		15	
Input power at 1 dB compression	LO = +13 dBm	dBm		0	
Input two-tone third-order intercept point	LO = +13 dBm	dBm		+10	
OUTPUT PARAMETERS	CONDITION	UNITS	MIN.	TYP.	MAX.
IF frequency range	3 dB bandwidth	GHz	DC		1.5
IF VSWR (IF = -10 dBm, LO = +13 dBm)		Ratio		2.75:1	

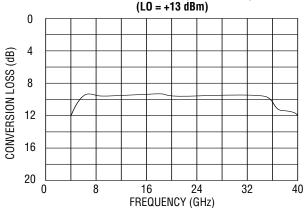


SBE0440LW1 TYPICAL TEST DATA





CONVERSION LOSS (IF = 100 MHz) (LO = +13 dBm)



SINGLE-TONE (m) RF x (n) LO RELATIVE SPUR LEVEL (dBc) (AVERAGE MIDBAND RF, LO, IF FREQUENCIES,

RF :	= -10	dBm,	LO	= +13	dBm)

(m) R	SPUF F x (-	RF TEST FREQ. (GHz)	LO TEST FREQ. (GHz)	SPUR LEVEL (dBc)
1	Х	1	10.75	11.25	-33
1	Χ	2	14.5	7.5	REF
1	Χ	3	16.36	5.62	-30
2	Χ	1	7.16	14.8	-45
2	Χ	2	10.87	11.12	-50
2	Χ	3	13.1	8.9	-45
3	Χ	1	5.37	16.6	-40
3	Χ	2	8.7	13.3	-40
3	Χ	3	10.91	11.08	-50

MAXIMUM RATINGS

Specification temperature.....+25°C Operating temperature-54 to +85°C Storage temperature-65 to +125°C

NOTE: Test data supplied at 25°C; conversion loss and 2LO-to-RF isolation.

OUTLINE DRAWING .560 [14.22] .160 [4.06] .240 [6.10] _C .042 [1.07] .260 6.60] .436 [11.07] .520 [13.21] RF IN LO IN .067 [1.70] DIA. THRU TYPE 2.9 MM MOUNTING HOLES (4 PLACES) FIELD REPLACEABLE .280 IF OUT (TYPE SMA FIELD REPLACEABLE FEMALE CONNECTOR FEMALE CONNECTOR) (TYP. 2 PLACES) .280 .290 -.100 [2.54] [7.37] .195 [4.95] .38 [9.65] OPTIONAL SPACER PLATE TYP. NOTE: All dimensions shown in brackets [] are in millimeters.